





248NQ100-2 SCHOTTKY RECTIFIER



Features

- 175°C T_J operation
- Unique high power, Half-Pak module
- Replaces three parallel DO-5' S
- Easier to mount and lower profile than DO-5' S
- High purity, high temperature epoxy encapsulation for enhanced
- mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- Baseplate: Nickel plated; Terminals: Nickel plated
- This is a Pb Free Device
- . All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition		Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-		100	V
Average Forward Current	I _{F(AV)}	50% duty cycle @T _C =120°C, rectangular wave form		240	А
	IFSM	8.3 ms, half Sine pulse		3960	Α
Maximum Peak One Cycle Non- Repetitive Surge Current		5 us sine or 3 us rect. pulse	Following and rated load condition and with rated V _{RRM} applied	25500	A
		10 ms sine or 6 ms rect. pulse		3300	
Non-Repetitive Avalanche Energy	E _{AS}	T _J =25°C,I _{AS} =1A,L=30 mH		15	mJ
Repetitive Avalanche Current	I _{AR}	Current decaying linearly to zero in 1 µsec Frequency limited by T_J max. V_A =1.5 \times V_R typical		1	А

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •







Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V_{F1}	@ 240A, Pulse, T _J = 25 °C	0.77	0.95	V
	V_{F2}	@ 240A, Pulse, T _J = 125 °C	0.62	0.72	V
Reverse Current*	I _{R1}	@V _R = rated V _R T _J = 25 °C	0.032	6	mA
	I _{R2}	$@V_R = \text{rated } V_R T_J = 125 ^{\circ}\text{C}$	12	80	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 ^{\circ}C$ $f_{SIG} = 1MHz$	5277	5500	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

 $^{^*}$ Pulse width < 300 μ s, duty cycle < 2%

Thermal-Mechanical Specifications:

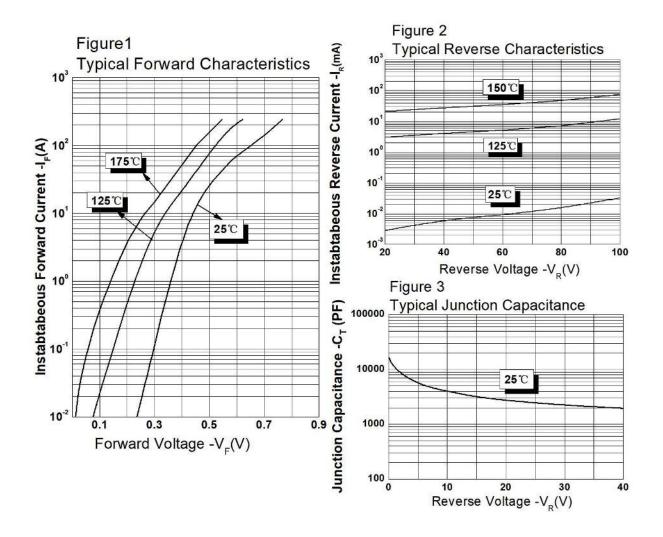
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +175	°C
Storage Temperature	T _{stg}	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case	Rejc	DC operation	0.19	°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.05	°C/W
Mounting Torque	Тм	Non-lubricated threads	Mounting 23(min) Torque 29(max) Terminal 35(min) Torque 46(max)	- Kg-cm
Approximate Weight	wt	-	25.6	g
Case Style	PRM1-1			







Ratings and Characteristics Curves



Ordering Information

Device	Package	Shipping	
248NQ100-2	PRM1-1(Pb-Free)	27pcs/ box	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXX is YYWW

1st row SS YYWW
2nd row 248NQ100-2
SS = SS
YY = Year
WW = Week

Cautions: Molding resin Epoxy resin UL:94V-0

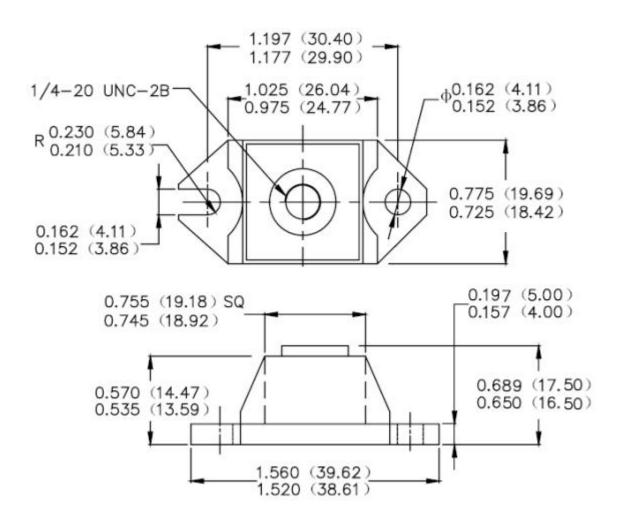
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Mechanical Dimensions PRM1-1 (Inches/Millimeters)



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